

74LVX161284A Low Voltage IEEE 161284 Translating Transceiver

General Description

The LVX161284A contains eight bidirectional data buffers and eleven control/status buffers to implement a full IEEE 1284 compliant interface. The device supports the IEEE 1284 standard, with the exception of output slew rate, and is intended to be used in an Extended Capabilities Port mode (ECP). The pinout allows for easy connection from the Peripheral (A-side) to the Host (cable side).

Outputs on the cable side can be configured to be either open drain or high drive (± 14 mA) and are connected to a separate power supply pin (V_{CC} —cable) to allow these outputs to be driven by a higher supply voltage than the A-side. The pull-up and pull-down series termination resistance of these outputs on the cable side is optimized to drive an external cable. In addition, all inputs (except HLH) and outputs on the cable side contain internal pull-up resistors connected to the V_{CC} —cable supply to provide proper termination and pull-ups for open drain mode.

Outputs on the Peripheral side are standard low-drive CMOS outputs designed to interface with 3V logic. The DIR input controls data flow on the A_1 – A_8 / B_1 – B_8 transceiver pins.

Features

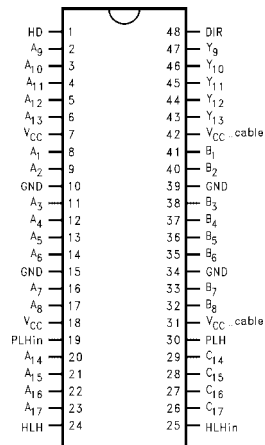
- Supports IEEE 1284 Level 1 and Level 2 signaling standards for bidirectional parallel communications between personal computers and printing peripherals with the exception of output slew rate
- Translation capability allows outputs on the cable side to interface with 5V signals
- All inputs have hysteresis to provide noise margin
- B and Y output resistance optimized to drive external cable
- B and Y outputs in high impedance mode during power down
- Inputs and outputs on cable side have internal pull-up resistors
- Flow-through pin configuration allows easy interface between the “Peripheral and Host”
- Replaces the function of two (2) 74ACT1284 devices

Ordering Code

Order Number	Package Number	Package Description
74LVX161284AMTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter “X” to the ordering code.

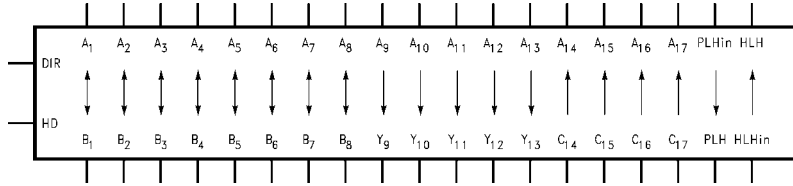
Connection Diagram



Pin Descriptions

Pin Names	Description
HD	High Drive Enable Input (Active HIGH)
DIR	Direction Control Input
A_1 – A_8	Inputs or Outputs
B_1 – B_8	Inputs or Outputs
A_9 – A_{13}	Inputs
Y_9 – Y_{13}	Outputs
A_{14} – A_{17}	Outputs
C_{14} – C_{17}	Inputs
PLH _{IN}	Peripheral Logic HIGH Input
PLH	Peripheral Logic HIGH Output
HLH _{IN}	Host Logic HIGH Input
HLH	Host Logic HIGH Output

Logic Symbol



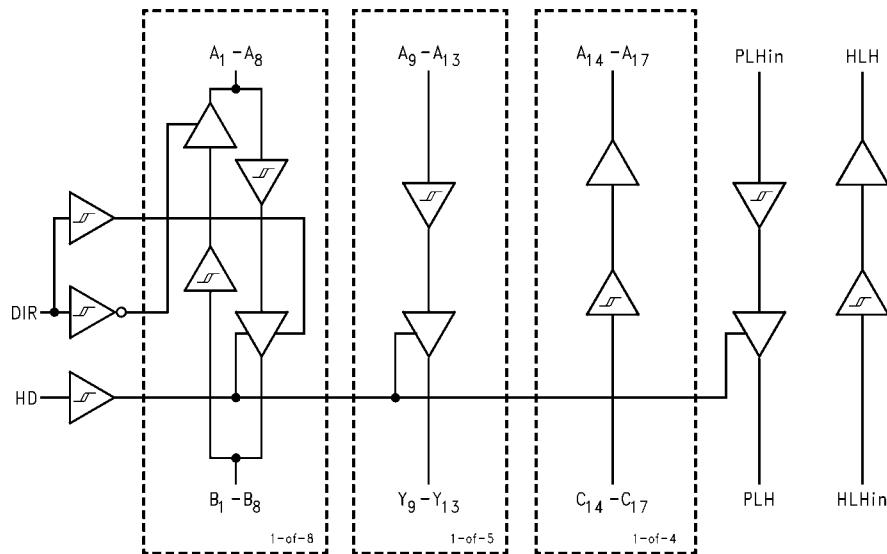
Truth Table

Inputs		Outputs
DIR	HD	
L	L	B ₁ -B ₈ Data to A ₁ -A ₈ , and A ₉ -A ₁₃ Data to Y ₉ -Y ₁₃ (Note 1) C ₁₄ -C ₁₇ Data to A ₁₄ -A ₁₇ PLH Open Drain Mode
L	H	B ₁ -B ₈ Data to A ₁ -A ₈ , and A ₉ -A ₁₃ Data to Y ₉ -Y ₁₃ C ₁₄ -C ₁₇ Data to A ₁₄ -A ₁₇
H	L	A ₁ -A ₈ Data to B ₁ -B ₈ (Note 2) A ₉ -A ₁₃ Data to Y ₉ -Y ₁₃ (Note 1) C ₁₄ -C ₁₇ Data to A ₁₄ -A ₁₇ PLH Open Drain Mode
H	H	A ₁ -A ₈ Data to B ₁ -B ₈ A ₉ -A ₁₃ Data to Y ₉ -Y ₁₃ C ₁₄ -C ₁₇ Data to A ₁₄ -A ₁₇

Note 1: Y₉-Y₁₃ Open Drain Outputs

Note 2: B₁-B₈ Open Drain Outputs

Logic Diagram



Absolute Maximum Ratings ^(Note 3)		Recommended Operating Conditions						
Supply Voltage		Supply Voltage						
V_{CC}	-0.5V to +4.6V	V_{CC}	3.0V to 3.6V					
$V_{CC-Cable}$	-0.5V to +7.0V	$V_{CC-Cable}$	3.0V to 5.5V					
$V_{CC-Cable}$ Must Be $\geq V_{CC}$		DC Input Voltage (V_i)						
Input Voltage (V_i)—(Note 4)		Open Drain Voltage (V_O)						
$A_1-A_{13}, PLH_{IN}, DIR, HD$	-0.5V to $V_{CC} + 0.5V$	0V to V_{CC}						
$B_1-B_8, C_{14}-C_{17}, HLH_{IN}$	-0.5V to +5.5V (DC)	0V to 5.5V						
$B_1-B_8, C_{14}-C_{17}, HLH_{IN}$	-2.0V to +7.0V*	Operating Temperature (T_A)						
	*40 ns Transient	-40°C to +85°C						
Output Voltage (V_O)								
$A_1-A_8, A_{14}-A_{17}, HLH$	-0.5V to $V_{CC} + 0.5V$							
B_1-B_8, Y_9-Y_{13}, PLH	-0.5V to +5.5V (DC)							
B_1-B_8, Y_9-Y_{13}, PLH	-2.0V to +7.0V*							
	*40 ns Transient							
DC Output Current (I_O)								
A_1-A_8, HLH	± 25 mA							
B_1-B_8, Y_9-Y_{13}	± 50 mA							
PLH (Output LOW)	84 mA							
PLH (Output HIGH)	-50 mA							
Input Diode Current (I_{IK})—(Note 4)								
DIR, HD, $A_9-A_{13}, PLH, HLH, C_{14}-C_{17}$	-20 mA							
Output Diode Current (I_{OK})								
$A_1-A_8, A_{14}-A_{17}, HLH$	± 50 mA							
B_1-B_8, Y_9-Y_{13}, PLH	-50 mA							
DC Continuous V_{CC} or Ground Current		± 200 mA						
Storage Temperature		-65°C to +150°C						
ESD (HBM) Last Passing Voltage		2000V						
<p>Note 3: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.</p> <p>Note 4: Either voltage limit or current limit is sufficient to protect inputs.</p>								
DC Electrical Characteristics								
Symbol	Parameter	V_{CC} (V)	$V_{CC-Cable}$ (V)	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$		Units	Conditions	
				Guaranteed Limits				
V_{IK}	Input Clamp Diode Voltage	3.0	3.0	-1.2		V	$I_i = -18$ mA	
V_{IH}	Minimum HIGH Level Input Voltage	$A_n, B_n, PLH_{IN}, DIR, HD$	3.0-3.6	3.0-5.5	2.0		V	
		C_n	3.0-3.6	3.0-5.5	2.3			
		HLH_{IN}	3.0-3.6	3.0-5.5	2.6			
V_{IL}	Maximum LOW Level Input Voltage	$A_n, B_n, PLH_{IN}, DIR, HD$	3.0-3.6	3.0-5.5	0.8		V	
		C_n	3.0-3.6	3.0-5.5	0.8			
		HLH_{IN}	3.0-3.6	3.0-5.5	1.6			
ΔV_T	Minimum Input Hysteresis	$A_n, B_n, PLH_{IN}, DIR, HD$	3.3	5.0	0.4		V	$V_T^+ - V_T^-$
		C_n	3.3	5.0	0.8			
		HLH_{IN}	3.3	5.0	0.2			
V_{OH}	Minimum HIGH Level Output Voltage	A_n, HLH	3.0	3.0	2.8		V	$I_{OH} = -50$ μ A
			3.0	3.0	2.4			$I_{OH} = -4$ mA
		B_n, Y_n	3.0	3.0	2.0			$I_{OH} = -14$ mA
		B_n, Y_n	3.0	4.5	2.23			$I_{OH} = -14$ mA
		PLH	3.15	3.15	3.1			$I_{OH} = -500$ μ A

DC Electrical Characteristics (Continued)

Symbol	Parameter		V _{CC} (V)	V _{CC—Cable} (V)	T _A = -40°C to +85°C	Units	Conditions	
					Guaranteed Limits			
V _{OL}	Maximum LOW Level Output Voltage	A _n , HLH	3.0	3.0	0.2	V	I _{OL} = 50 μA I _{OL} = 4 mA	
			3.0	3.0	0.4			
		B _n , Y _n	3.0	3.0	0.8		I _{OL} = 14 mA I _{OL} = 14 mA	
			3.0	4.5	0.77			
		PLH	3.0	3.0	0.95		I _{OL} = 84 mA	
PLH	3.0	4.5	0.9	I _{OL} = 84 mA				
R _D	Maximum Output Impedance	B ₁ –B ₈ , Y ₉ –Y ₁₃	3.3	3.3	60	Ω	(Note 5)(Note 7)	
			3.3	5.0	55			
	Minimum Output Impedance	B ₁ –B ₈ , Y ₉ –Y ₁₃	3.3	3.3	30		(Note 5)(Note 7)	
			3.3	5.0	35			
R _P	Maximum Pull-Up Resistance	B ₁ –B ₈ , Y ₉ –Y ₁₃ , C ₁₄ –C ₁₇	3.3	3.3	1650	Ω		
			3.3	5.0	1650			
	Minimum Pull-Up Resistance	B ₁ –B ₈ , Y ₉ –Y ₁₃ , C ₁₄ –C ₁₇	3.3	3.3	1150			
			3.3	5.0	1150			
I _{IH}	Maximum Input Current in HIGH State	A ₉ –A ₁₃ , PLH _{IN} , HD, DIR, HLH _{IN}	3.6	3.6	1.0	μA	V _I = 3.6V	
		C ₁₄ –C ₁₇	3.6	3.6	50.0		V _I = 3.6V	
		C ₁₄ –C ₁₇	3.6	5.5	100		V _I = 5.5V	
I _{IL}	Maximum Input Current in LOW State	A ₉ –A ₁₃ , PLH _{IN} , HD, DIR, HLH _{IN}	3.6	3.6	-1.0	μA	V _I = 0.0V	
		C ₁₄ –C ₁₇	3.6	3.6	-3.5		mA	V _I = 0.0V
		C ₁₄ –C ₁₇	3.6	5.5	-5.0		mA	V _I = 0.0V
I _{OZH}	Maximum Output Disable Current (HIGH)	A ₁ –A ₈	3.6	3.6	20	μA	V _O = 3.6V	
		B ₁ –B ₈	3.6	3.6	50		V _O = 3.6V	
		B ₁ –B ₈	3.6	5.5	100		V _O = 5.5V	
I _{OZL}	Maximum Output Disable Current (LOW)	A ₁ –A ₈	3.6	3.6	-20	μA	V _O = 0.0V	
		B ₁ –B ₈	3.6	3.6	-3.5			mA
		B ₁ –B ₈	3.6	5.5	-5.0			mA
I _{OFF}	Power Down Output Leakage	B ₁ –B ₈ , Y ₉ –Y ₁₃ , PLH	0.0	0.0	100	μA	V _O = 5.5V	
I _{OFF}	Power Down Input Leakage	C ₁₄ –C ₁₇ , HLH _{IN}	0.0	0.0	100	μA	V _I = 5.5V	
I _{OFF—ICC}	PowerDown Leakage to V _{CC}		0.0	0.0	250	μA	(Note 6)	
I _{OFF—ICC2}	Power Down Leakage to V _{CC—Cable}		0.0	0.0	250	μA	(Note 6)	
I _{CC}	Maximum Supply Current		3.6	3.6	45	mA	V _I = V _{CC} or GND	
			3.6	5.5	70		V _I = V _{CC} or GND	

Note 5: Output impedance is measured with the output active LOW and active HIGH (HD = HIGH).

Note 6: Power-down leakage to V_{CC} or V_{CC—Cable} is tested by simultaneously forcing all pins on the cable-side (B₁–B₈, Y₉–Y₁₃, PLH, C₁₄–C₁₇ and HLH_{IN}) to 5.5V and measuring the resulting I_{CC} or I_{CC—Cable}.

Note 7: This parameter is guaranteed but not tested, characterized only.

AC Electrical Characteristics

Symbol	Parameter	T _A = -40°C to +85°C V _{CC} = 3.0V-3.6V V _{CC-Cable} = 4.5V-5.5V		Units	Figure Number
		Min	Max		
t _{PHL}	A ₁ -A ₈ to B ₁ -B ₈	1.0	8.5	ns	Figure 1
t _{PLH}	A ₁ -A ₈ to B ₁ -B ₈	1.0	8.5	ns	Figure 2
t _{PHL}	B ₁ -B ₈ to A ₁ -A ₈	1.0	14.0	ns	Figure 3
t _{PLH}	B ₁ -B ₈ to A ₁ -A ₈	1.0	14.0	ns	Figure 3
t _{PHL}	A ₉ -A ₁₃ to Y ₉ -Y ₁₃	1.0	8.5	ns	Figure 1
t _{PLH}	A ₉ -A ₁₃ to Y ₉ -Y ₁₃	1.0	8.5	ns	Figure 2
t _{PHL}	C ₁₄ -C ₁₇ to A ₁₄ -A ₁₇	1.0	10.0	ns	Figure 3
t _{PLH}	C ₁₄ -C ₁₇ to A ₁₄ -A ₁₇	1.0	10.0	ns	Figure 3
t _{SKEW}	LH-LH or HL-HL		2.0	ns	(Note 8)
t _{PHL}	PLH _{IN} to PLH	1.0	8.5	ns	Figure 1
t _{PLH}	PLH _{IN} to PLH	1.0	8.5	ns	Figure 2
t _{PHL}	HLH _{IN} to HLH	1.0	10.0	ns	Figure 3
t _{PLH}	HLH _{IN} to HLH	1.0	12.0	ns	Figure 3
t _{PHZ}	Output Disable Time	1.0	10.0		
t _{PLZ}	DIR to A ₁ -A ₈	1.0	10.0	ns	Figure 4
t _{PZH}	Output Enable Time	1.0	10.0		
t _{PZL}	DIR to A ₁ -A ₈	1.0	10.0	ns	Figure 5
t _{PHZ}	Output Disable Time	1.0	13.0		
t _{PLZ}	DIR to B ₁ -B ₈	1.0	10.0	ns	Figure 6
t _{pEN}	Output Enable Time HD to B ₁ -B ₈ , Y ₉ -Y ₁₃	1.0	8.0	ns	Figure 2
t _{pDIS}	Output Disable Time HD to B ₁ -B ₈ , Y ₉ -Y ₁₃	1.0	12.0	ns	Figure 2

Note 8: t_{SKEW} is measured for common edge output transitions and compares the measured propagation delay for a given path type:

- (i) A₁-A₈ to B₁-B₈, A₉-A₁₃ to Y₉-Y₁₃
- (ii) B₁-B₈ to A₁-A₈
- (iii) C₁₄-C₁₇ to A₁₄-A₁₇

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C _{IN}	Input Capacitance	3	pF	V _{CC} = 0.0V (HD, DIR, A ₉ -A ₁₃ , C ₁₄ -C ₁₇ , PLH _{IN} and HLH _{IN})
C _{I/O} (Note 9)	I/O Pin Capacitance	5	pF	V _{CC} = 3.3V

Note 9: C_{I/O} is measured at frequency = 1 MHz, per MIL-STD-883B, Method 3012

AC Loading and Waveforms

Pulse Generator for all pulses: Rate ≤ 1.0 MHz; $Z_0 \leq 50\Omega$; $t_f \leq 2.5$ ns, $t_r \leq 2.5$ ns.

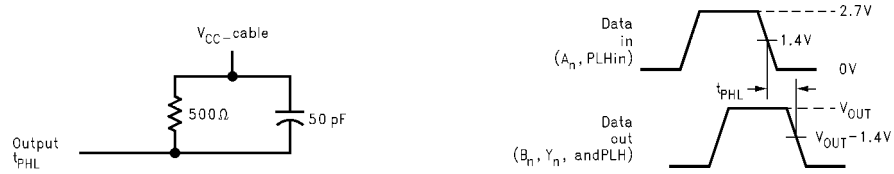


FIGURE 1. t_{PHL} Test Load and Waveforms
A₁-A₈ to B₁-B₈
A₉-A₁₃ to Y₉-Y₁₃
PLHin to PLH

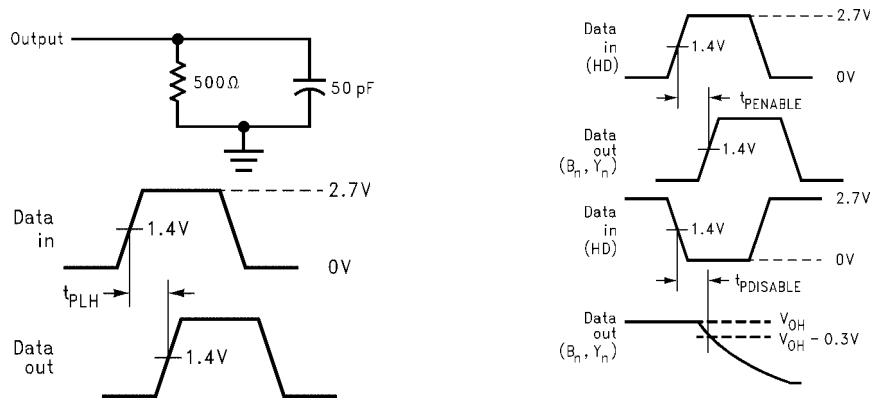


FIGURE 2. t_{PLH} , t_{PEn} , t_{PDis} Test Load and Waveforms
A₁-A₈ to B₁-B₈, A₉-A₁₃ to Y₉-Y₁₃
PLHin to PLH, HD to B₁-B₈, Y₉-Y₁₃, PLH

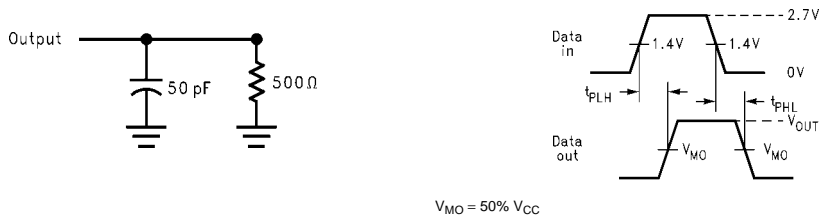


FIGURE 3. t_{PHL} , t_{PLH} Test Load and Waveforms
B₁-B₈ to A₁-A₈, C₁₄-C₁₇ to A₁₄-A₁₇, HLHin to HLH

AC Loading and Waveforms (Continued)

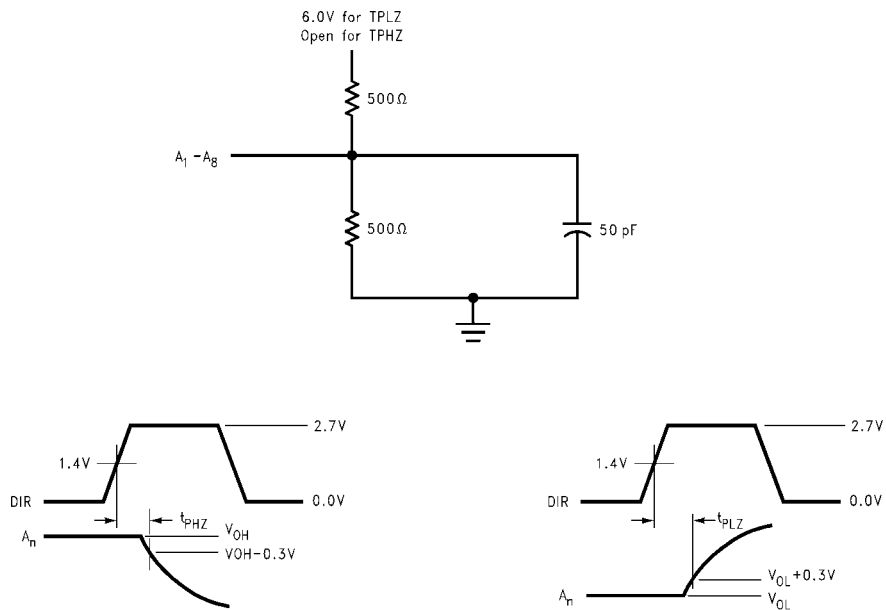


FIGURE 4. t_{PHZ} and t_{PLZ} Test Load and Waveforms, DIR to A₁-A₈

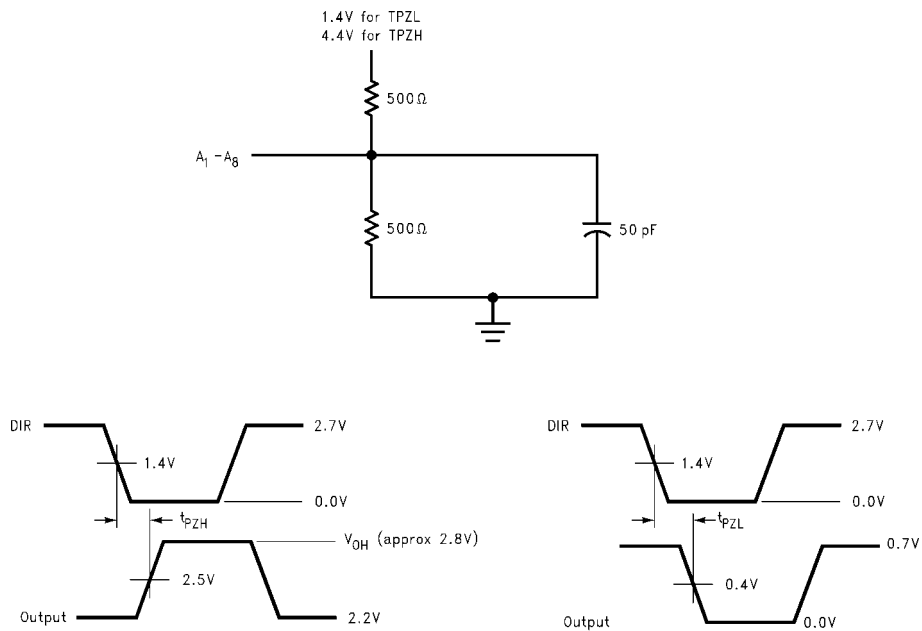


FIGURE 5. t_{PZH} and t_{PZL} Test Load and Waveforms, DIR to A₁-A₈

AC Loading and Waveforms (Continued)

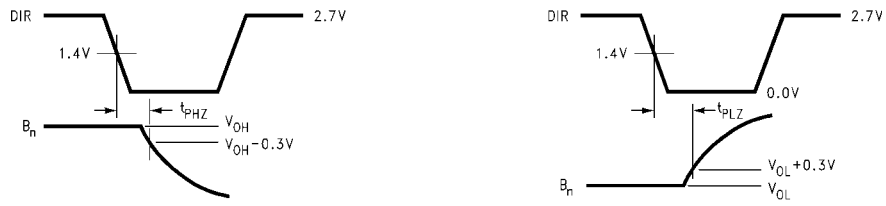
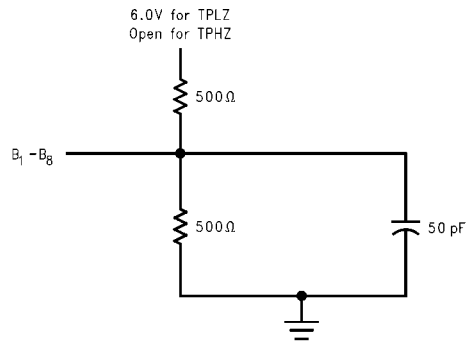
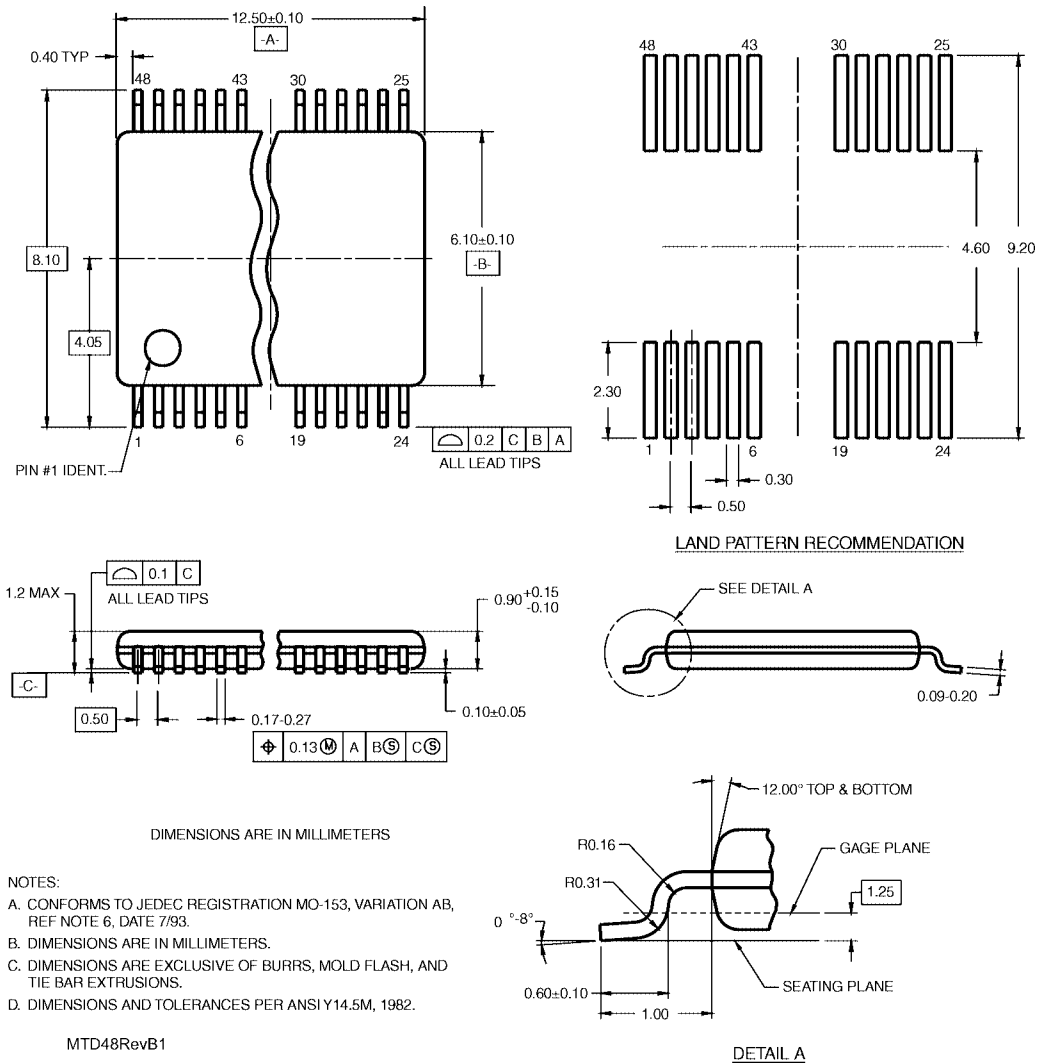


FIGURE 6. t_{PHZ} and t_{PLZ} Test Load and Waveforms
DIR to B_1-B_8

Physical Dimensions inches (millimeters) unless otherwise noted



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